

LIST OF PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

Applicant(s): M.A. Shbib et al.

Case: 41-10

Serial No.: ~~78A~~ 10/719/95

Filing Date: November 21, 2003

Group: ~~78A~~ 28/3

U.S. PATENT DOCUMENTS

| EXAMINER INITIAL | DOCUMENT NO. | DATE | NAME | CLASS/SUBCLASS | FILING DATE IF APPROPRIATE |
|---------------------|--------------|----------|-----------|----------------|-------------------------------|
| CC | 1. 6,461,902 | 10/08/02 | Xu et al. | 438/163 | - |

FOREIGN PATENT DOCUMENTS

| EXAMINER INITIAL | DOCUMENT NO. | DATE | COUNTRY | CLASS/SUBCLASS | TRANSLATION YES NO | |
|---------------------|--------------|------|---------|----------------|-----------------------|---|
| / | / | / | / | / | / | / |

OTHER DOCUMENTS

| EXAMINER INITIAL | REF NO. | AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC. |
|---------------------|---------|--|
| CC | 1. | J. Cai et al., "A Partial SOI Technology for Single-Chip RF Power Amplifiers," IEEE, pp. 40.3.1-40.3.4, 2001. |
| CC | 2. | S. Matsumoto et al., "A Quasi-SOI Power MOSFET for Radio Frequency Applications Formed by Reversed Silicon Wafer Direct Bonding," IEEE, pp. 1448-1453, 2001. |

Examiner

C. Chaudhari

Date Considered

1-05

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.